1 Electrical characteristics

Table 1. Absolute maximum ratings (limiting values)

Symbol	Parameter	Rating	Unit
P _{IN}	Input peak power RF _{IN} (CW mode)/all RF ports	+40	dBm
V _{ESD(HBM)}	Human body model, JESD22-A114-B, all I/O	Class 1B ⁽¹⁾	V
V _{ESD(MM)}	Machine model, JESD22-A115-A, all I/O	100	V
T _{device}	Device temperature	+125	°C
T _{stg}	Storage temperature	-55 to +150	
V _x	Bias voltage	25	V

1. Class 1B defined as passing 500 V, but fails after exposure to 1000V ESD pulse.

Symbol	Parameter		Unit		
	Falameter	Min.	Тур.	Max.	Unit
P _{IN}	RF input power		+33	+39	dBm
F _{OP}	Operating frequency	700		2700	MHz
T _{device}	Device temperature			+100	°C
T _{OP}	Operating temperature	-30		+85	
V _{BIAS}	Bias voltage	1		24	V



Symbol	Peremeter	Conditions		Value			
Symbol Paramete	Parameter	Conditions	Min.	Тур.	Max.	Unit	
C _{1V}	capacitance at 1 V bias	STPTIC-27L2	2.8	3.2	3.58	pF	
C _{2V}	capacitance at 2 V bias	STPTIC-27L2	2.43	2.7	2.97	pF	
C _{20V}	capacitance at 20V bias	STPTIC-27L2	0.63	0.69	0.75	pF	
C _{24V}	capacitance at 24 V bias	STPTIC-27L2	0.56	0.61	0.66	pF	
ΔC	Tuning range	Ratio between $C_{1V}/C_{24V}^{(1)}$	5/1				
ΙL	Leakage current	Measured with $V_{bias} = 24 V$			100	nA	
Q _{LB}	Quality factor	Measured at 700 MHz at 2 V	50	55			
Q _{HB}	Quality factor	Measured at 2700 MHz at 2 V	35	40			
		$V_{bias} = 1 V^{(2)(4)}$	60				
IP3	Third order intercept point	$V_{\text{bias}} = 24 V^{(2)(4)}$	80			dBm	
		$V_{\text{bias}} = 20 V^{(2)(4)}$	80				
		$V_{bias} = 1 V^{(3)(4)}$		-70	-65		
H2	Second harmonic	$V_{bias} = 24 V^{(3)(4)}$		-80	-75	dBm	
		$V_{\text{bias}} = 20 V^{(3)(4)}$			-65		
		$V_{\text{bias}} = 1 V^{(3)(4)}$		-55	-45		
H3	Third harmonic	$V_{\text{bias}} = 24 V^{(3)(4)}$		-85	-70	dBm	
		$V_{\text{bias}} = 20 \ V^{(3)(4)}$			-70		
+	Transition time	Average for any transition between C_{min} to $C_{max}^{(5)}$		50			
t _T		Average transition between C_{max} to $C_{min}^{(5)}$		30		μs	

Table 3. Representative performance	(T _{amb} = 25 °C otherwise specified)

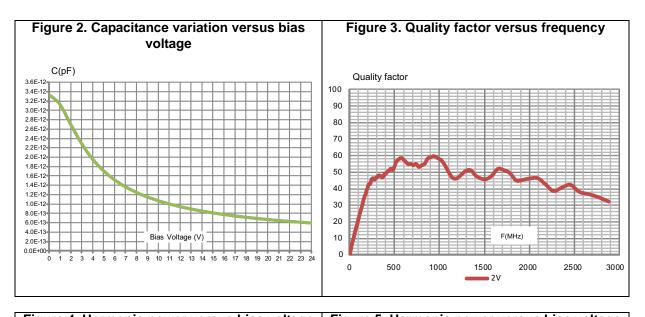
1. Measured at low frequency

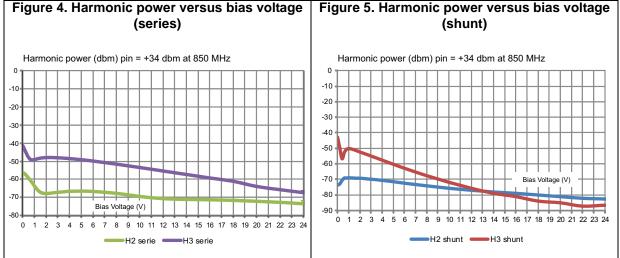
2. $F_1 = 894 \text{ MHz}, F_2 = 849 \text{ MHz}, P_1 = +25 \text{ dBm}, P_2 = +25 \text{ dBm}, 2f_1 - f_2 = 939 \text{ MHz}$

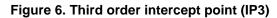
3. 850 MHz, P_{in} = +34 dBm, CW

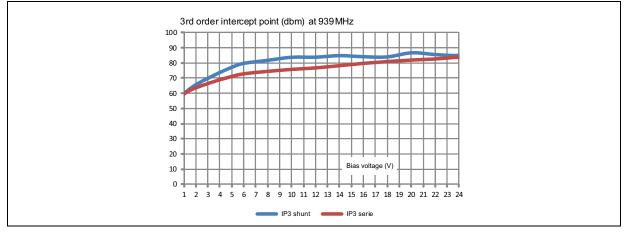
- 4. IP3 and harmonics are measured in the shunt configuration in a 50 Ω environment
- 5. One or both of $\mathsf{RF}_{\mathsf{in}}$ and $\mathsf{RF}_{\mathsf{out}}$ must be connected to DC ground, using the HVDAC turbo mode











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2 Package information

- Epoxy meets UL94, V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com.* ECOPACK[®] is an ST trademark.

2.1 Flip-Chip package information

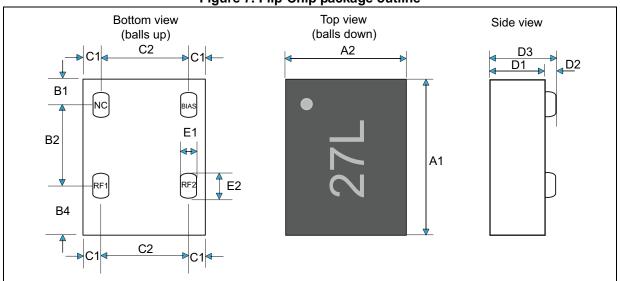


Figure 7. Flip-Chip package outline

The land pattern below is recommended for soldering the STPTIC-G2 on PCB.

NC stands for No Connect, this pad must not be connected on application board. Please leave this pad floating.

Table 4. Flip-	Chip package	dimensions
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Dimensions (in microns)	A1	A2	B1	B2	B4	C1	C2	D1	D2	D3	E1	E2
STPTIC-27L2	1000	750	140	500	360	105	540	225	90	315	125	165
Tolerance	±30	±30	±15	±10	±15	±15	±10	±20	±20	±40	±20	±20



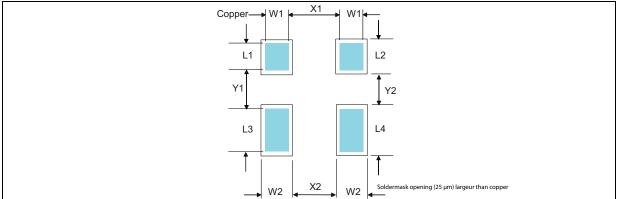




Table 5. Dimensions

Dimensions	L1	W1	L3	L2	W2	L4	X1	X2	Y1	Y2
Typical values (in microns)	160	160	260	210	210	310	320	270	240	190

2.2 Packing information

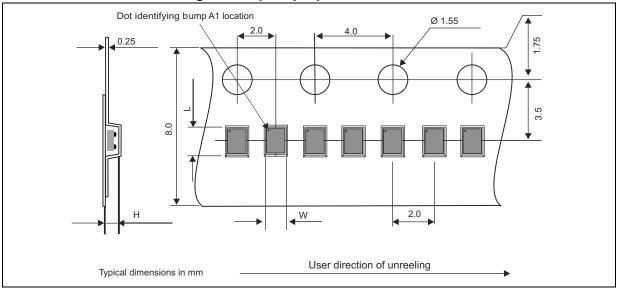


Figure 9. Flip-Chip tape and reel outline

Table 6. Dimensions

Pocket dimensions	L	W	Н
STPTIC-27L2	1070	820	380



Top view (balls down) Bottom view (balls up) A2 A1 A1 B2 B1 B1

Figure 10. Flip-Chip marking

Table 7. Pinout description

Pad / ball number	Pin name	Description
A1	DC bias	DC bias voltage
B1	RF2	RF input / output ⁽¹⁾
A2	NC	Not connected
B2	RF1	RF input / output

1. When connected in shunt, please connect RF2 (B1 ball) to GND



Reflow profile 3

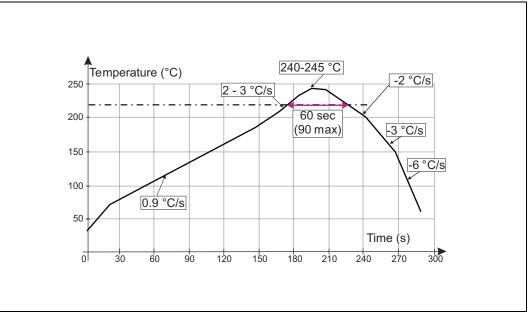


Figure 11. ST ECOPACK[®] recommended soldering reflow profile for PCB mounting



Minimize air convection currents in the reflow oven to avoid component movement.

Drafila	Valu	ue	
Profile	Typical	Max.	
Temperature gradient in preheat (T = 70-180 °C)	0.9 °C/s	3 °C/s	
Temperature gradient (T = 200-225 °C)	2 °C/s	3 °C/s	
Peak temperature in reflow	240-245 °C	260 °C	
Time above 220 °C	60 s	90 s	
Temperature gradient in cooling	-2 to -3 °C/s	-6 °C/s	
Time from 50 to 220 °C	C 160 to 220 s		

Table 8. Recommended values for soldering reflow



Ordering information 4

Figure 12. Ordering information scheme									
ST	PTIC	-	27	L	2	C5			
Manufacturer	Product family	-	<u>Capacitor</u> <u>value</u>	<u>Linearity</u>	Tuning	<u>Package</u>			
ST Microelectronics	PTIC Parascan™ tunable Integrated capacitor		15 = 1.5 pF 27 = 2.7 pF 33 = 3.3 pF 39 = 3.9 pF 47 = 4.7 pF 56 = 5.6 pF 68 = 6.8 pF 82 = 8.2 pF	F: Standard (x24) G: Standard (x24) L: High (x48)		M6 : QFN C5 : WLCSP 400 µm coating H5 : WLCSP			

Table 9. Ordering information

Part number	Marking	Base qty	Package	Delivery mode
STPTIC-27L2C5	27L	15 000	Flip-Chip	Tape and reel

Revision history 5

Date	Revision	Changes
04-Dec-2015	1	Initial release.



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